



SANYO Semiconductors

DATA SHEET

2SC5990

 — NPN Epitaxial Planar Silicon Transistor

DC / DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, flash.

Features

- Adoption of FBET and MBIT processes.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Narrow h_{FE} width.
- High allowable power dissipation.

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		100	V
Collector-to-Emitter Voltage	V_{CES}		100	V
Collector-to-Emitter Voltage	V_{CEO}		50	V
Emitter-to-Base Voltage	V_{EBO}		6	V
Collector Current	I_C		4	A
Collector Current (Pulse)	I_{CP}		7	A
Base Current	I_B		600	mA
Collector Dissipation	P_C	Mounted on a ceramic board (250mm \times 0.8mm)	1.3	W
		$T_c=25^\circ\text{C}$	3.5	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=40\text{V}, I_E=0\text{A}$			0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0\text{A}$			0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=2\text{V}, I_C=500\text{mA}$	250		400	
Gain-Bandwidth Product	f_T	$V_{CE}=10\text{V}, I_C=500\text{mA}$		400		MHz

Marking : FH

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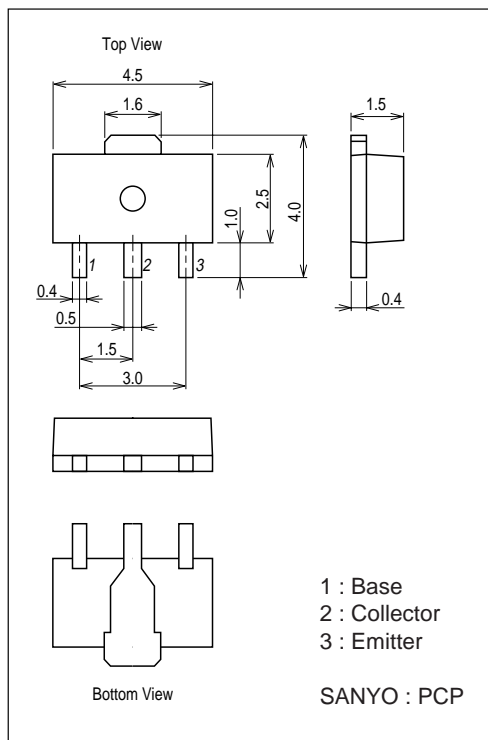
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output Capacitance	Cob	$V_{CB}=10V, f=1MHz$		15		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=1A, I_B=50mA$		65	100	mV
		$I_C=2A, I_B=100mA$		110	165	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=2A, I_B=100mA$		0.88	1.3	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0A$	100			V
Collector-to-Base Breakdown Voltage	$V_{(BR)CES}$	$I_C=100\mu A, R_{BE}=0\Omega$	100			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0A$	6			V
Turn-ON Time	t_{on}	See specified Test Circuit.		35		ns
Storage Time	t_{stg}	See specified Test Circuit.		300		ns
Fall Time	t_f	See specified Test Circuit.		20		ns

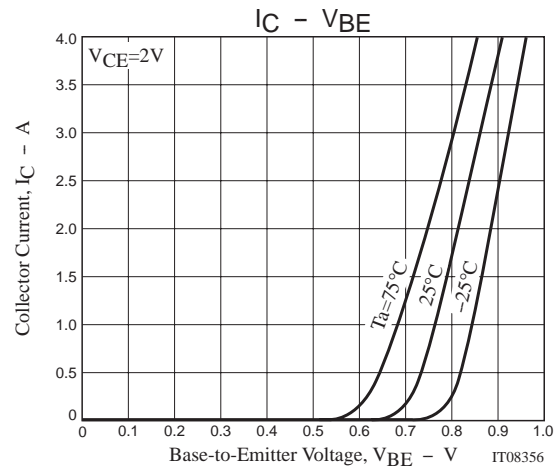
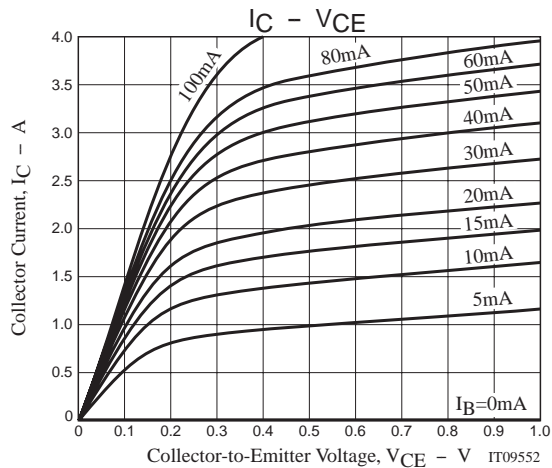
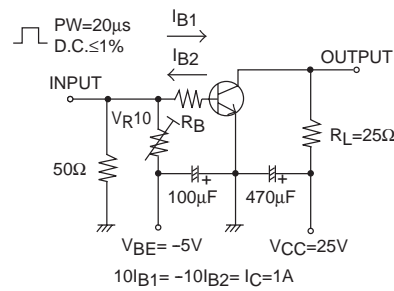
Package Dimensions

unit : mm

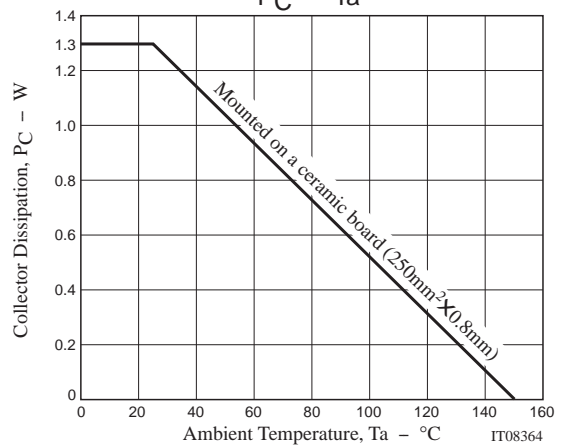
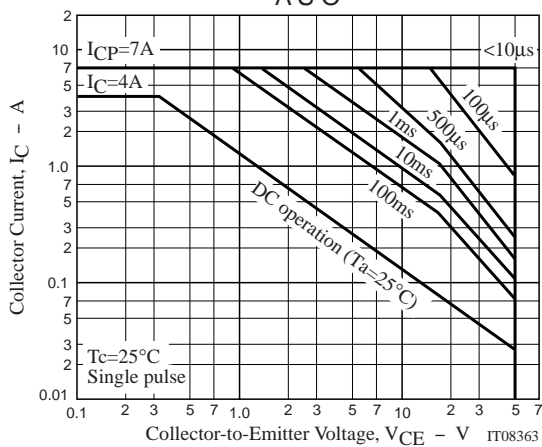
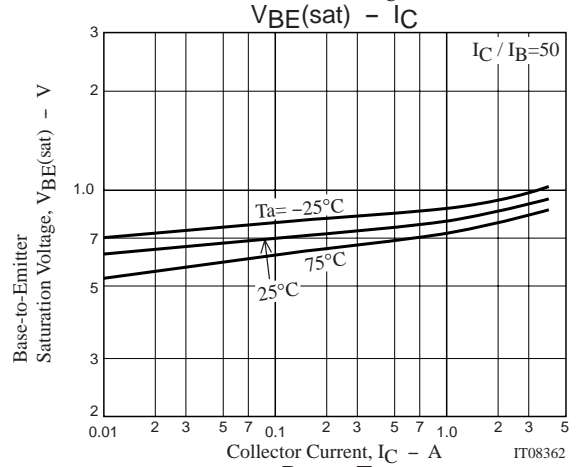
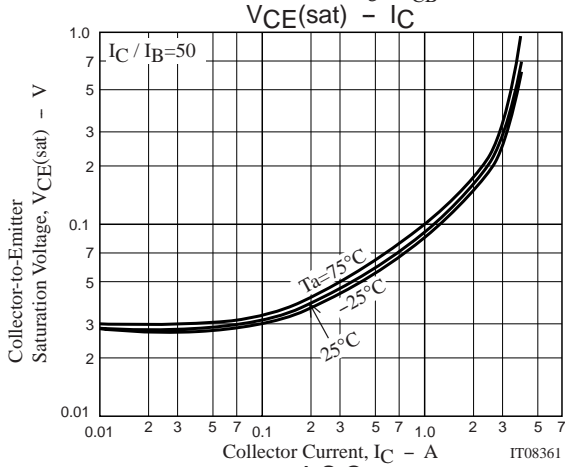
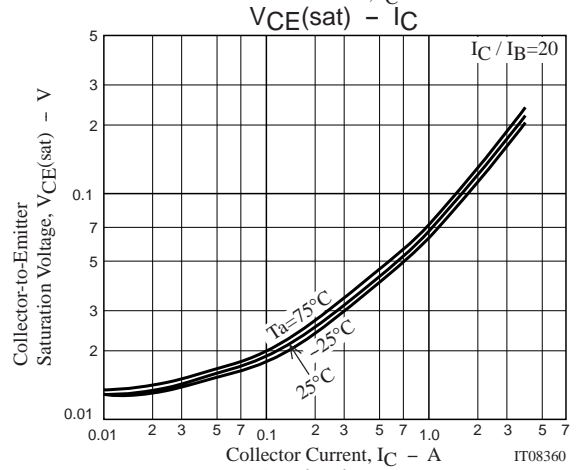
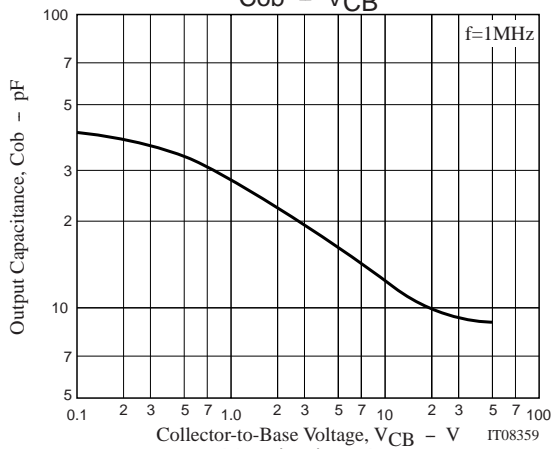
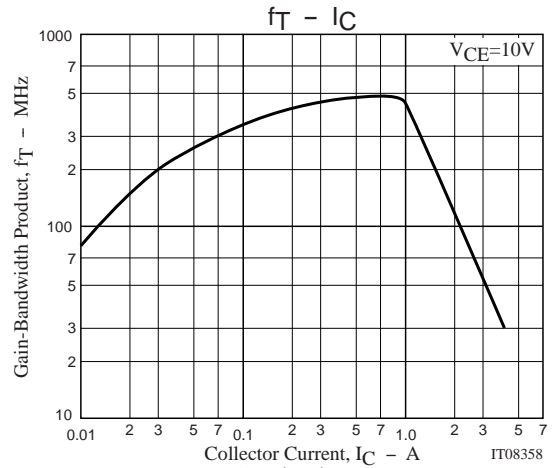
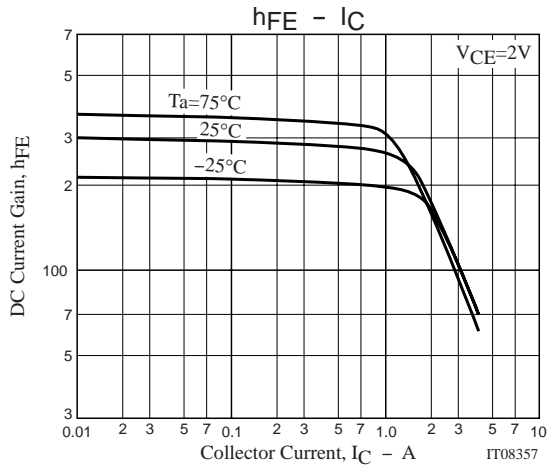
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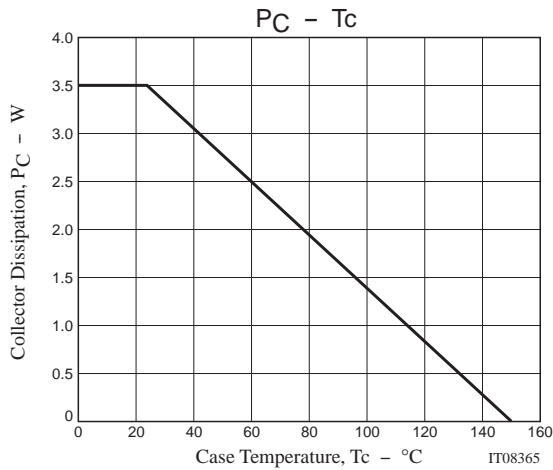


Switching Time Test Circuit



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